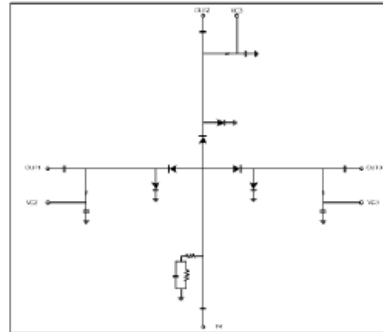


**Features**

- Frequency: 2-20GHz
- Insertion Loss: 0.9dB typ.
- Isolation: 50dB typ.
- P-1dB: 26dBm
- Input/Output: 50Ω
- Die Size: 1.92x 1.67x 0.1 mm

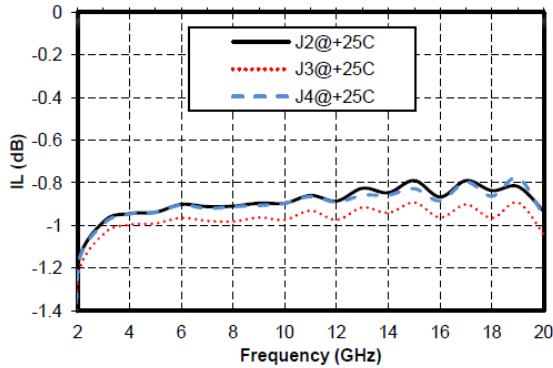
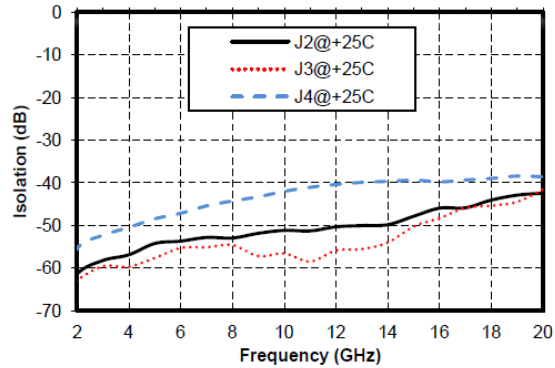
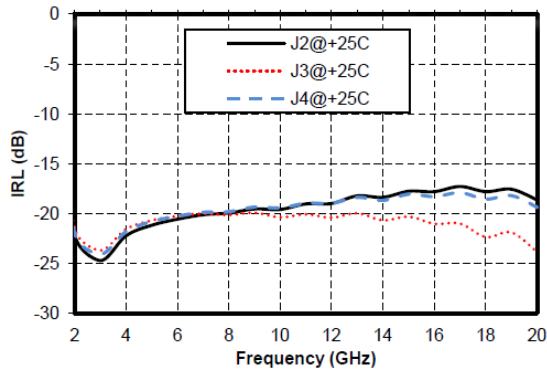
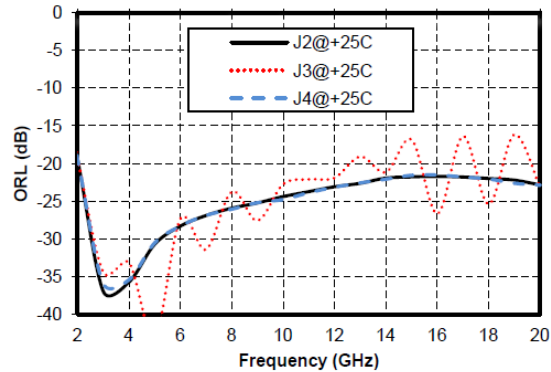
**Typical Applications**

- Test Instrumentation
- Microwave Radio & VSAT
- Military & Space
- Telecom Infrastructure
- Fiber Optics

**Functional Block Diagram**

**Electrical Specifications**

TA = +25°C

Parameters	Min.	Typ.	Max.	Units
Frequency Range	2-20			GHz
Insertion Loss	-	0.9	1.2	dB
Isolation	42	50	-	dB
Input Return Loss	17	19	-	dB
Output Return Loss	22	25	-	dB
P-1dB	-	26	-	dBm
Switching Speed	-	30	-	ns

**Insertion Loss vs.  
Operating Frequency**

**Isolation vs. Operating  
Frerquency**

**Input Return Loss vs.  
Operating Frequency**

**Output Return Loss vs.  
Operating Frequency**


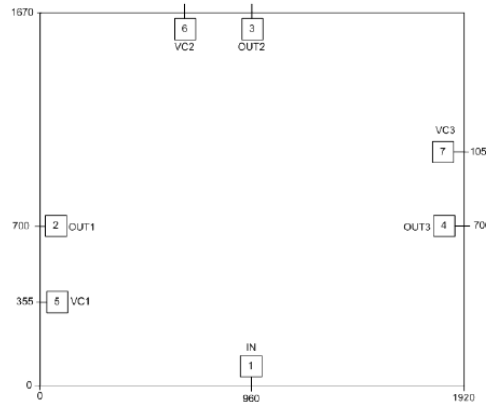
### Typical Driver Connections

CONTROL LEVEL (DC CURRENT)			RF OUTPUT STATE		
VC1	VC2	VC3	OUT1(J2)-IN(J1)	OUT2(J3)-IN(J1)	OUT3(J4)-IN(J1)
-10mA	+10mA	+10mA	Low Loss	Isolation	Isolation
+10mA	-10mA	+10mA	Isolation	Low Loss	Isolation
+10mA	+10mA	-10mA	Isolation	Isolation	Low Loss



### Outline Drawing

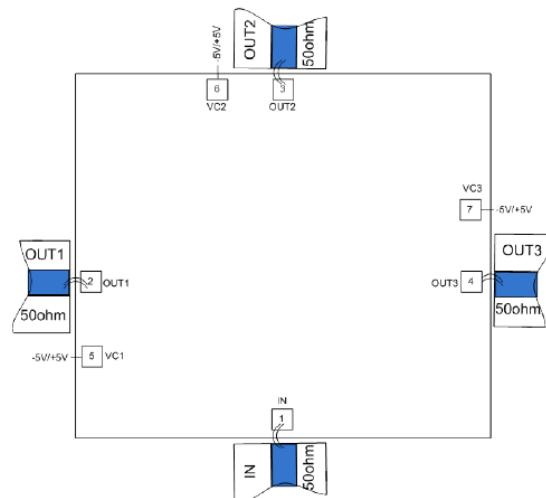
All Dimensions in  $\mu\text{m}$



### Pad Description

Pad	Function	Description
1	IN(J1)	RF signal input port
2,3,4	OUT1(J2), OUT2(J3), OUT3(J4)	RF signal output port
5,6,7	VC1, VC2, VC3	Signal control port
Die bottom	GND	Die bottom must be connected to RF/DC ground.

### Assembly Drawing



#### Notes:

1. Die thickness: 100um
2. Typical bond pad is 100\*100  $\mu\text{m}^2$
3. Bond pad metalization: Gold
4. Backside metalization: Gold
5. Backside of the die (GND)
6. No connection required for unlabeled bond pads

#### Maximum Ratings:

1. Maximum input voltage: 25V
2. Maximum input power: +31dBm CW
3. Operating temperature: -55°C to +85°C
4. Storage temperature: -65°C to +150°C